

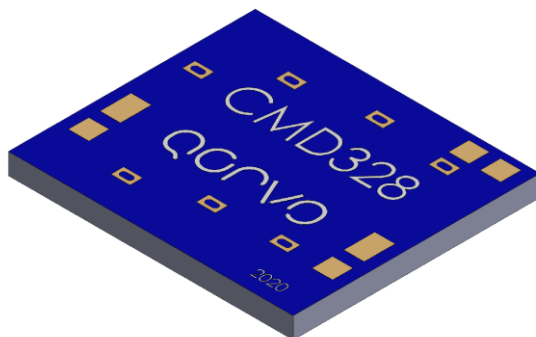


CMD328

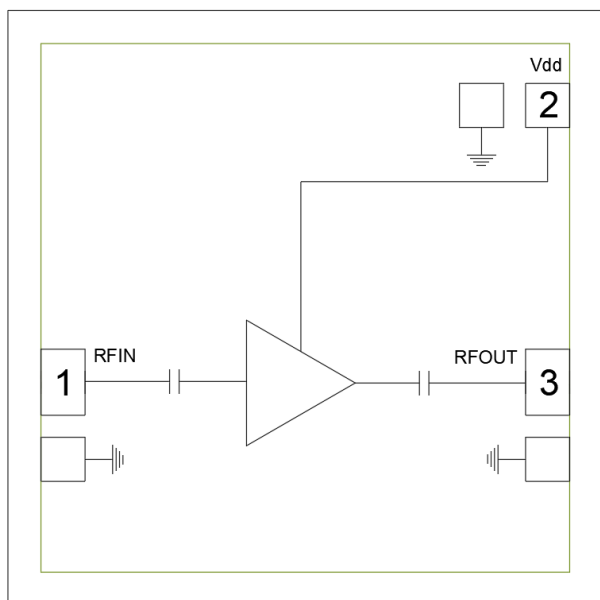
6-18 GHz Low Noise Amplifier

Product Overview

Qorvo's CMD328 is a broadband MMIC low noise amplifier in die form operating over the 6 to 18 GHz bandwidth. The CMD328 is ideally suited for EW and communications systems where small size and low power consumption are needed. The broadband device delivers greater than 27 dB of gain with a corresponding output 1 dB compression point of +12 dBm and a noise figure of 1.4 dB. The CMD328 is a 50 Ohm matched design thereby eliminating the need for external DC blocks and RF port matching. The CMD328 amplifier is the perfect alternative to costly hybrid amplifiers.



Functional Block Diagram



Key Features

- Ultra low noise figure
- High gain broadband performance
- Single supply voltage: +3.0V @ 52 mA
- Small die size

Performance is typical across frequency. Please reference electrical specification table and data plots for more details.

Applications

- EW systems
- Communications systems
- Low noise receiver systems

Ordering Information

Part No.	Description
CMD328	Low noise amplifier die
CMD328S2	Sample, 2 pieces

Absolute Maximum Ratings

Parameter	Rating
Drain Voltage, Vdd	5 V
RF Input Power	+20 dBm
Channel Temperature, T _{ch}	150 °C
Power Dissipation, P _{diss}	490 mW
Operating Temperature	-55 to 85 °C
Storage Temperature	-55 to 150 °C

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability.

Recommended Operating Conditions

Parameter	Min	Typ.	Max	Units
Vdd	2	3	4.5	V
Idd		52		mA
Temperature Range	-55	+25	+85	°C

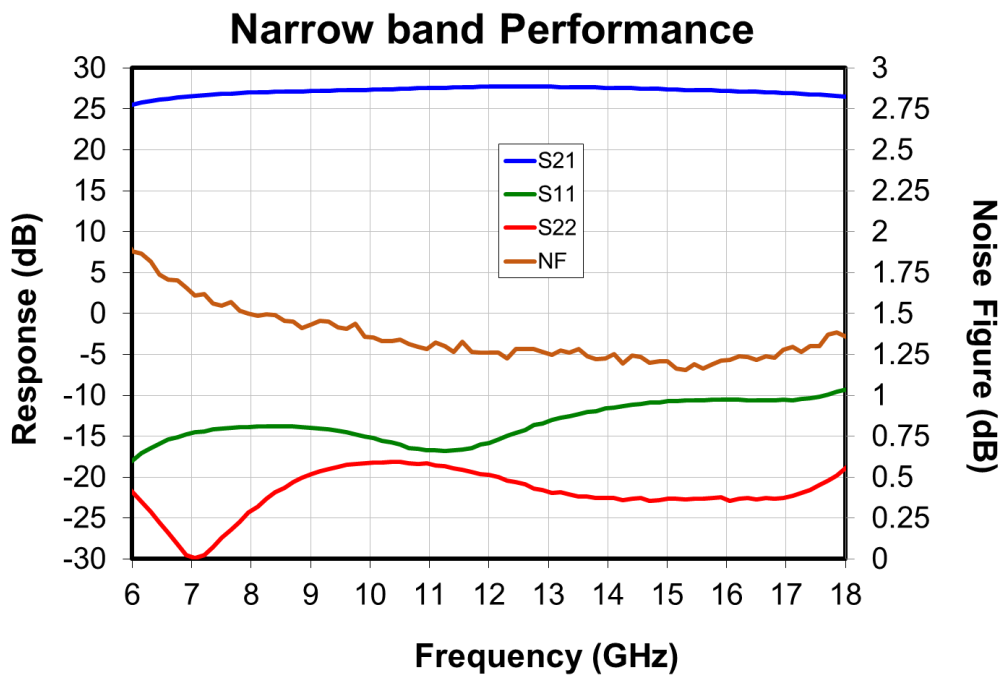
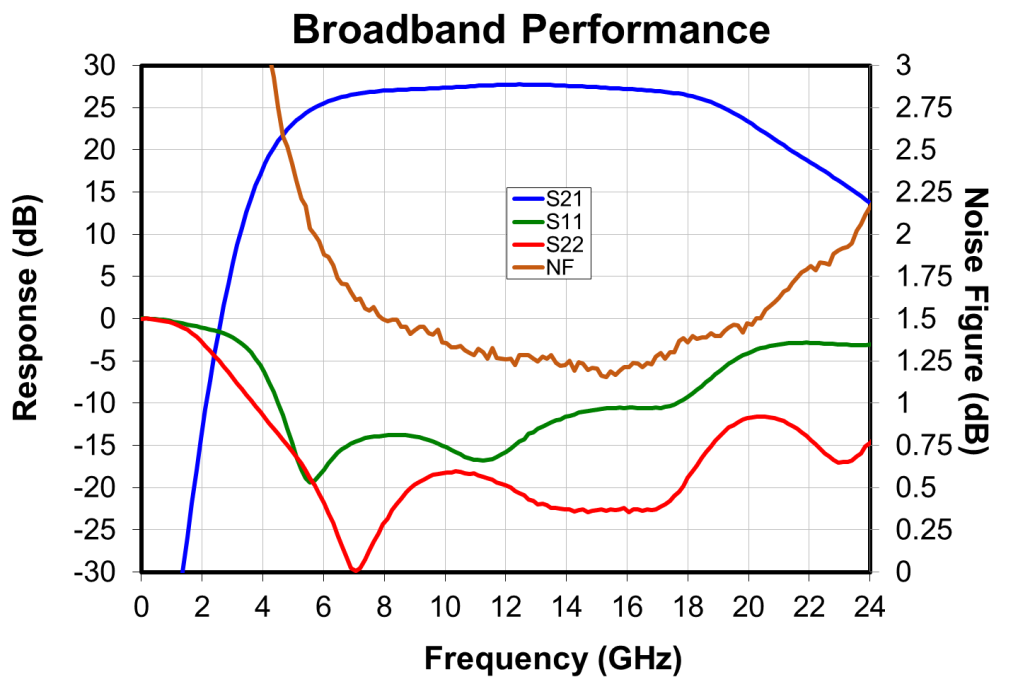
Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications

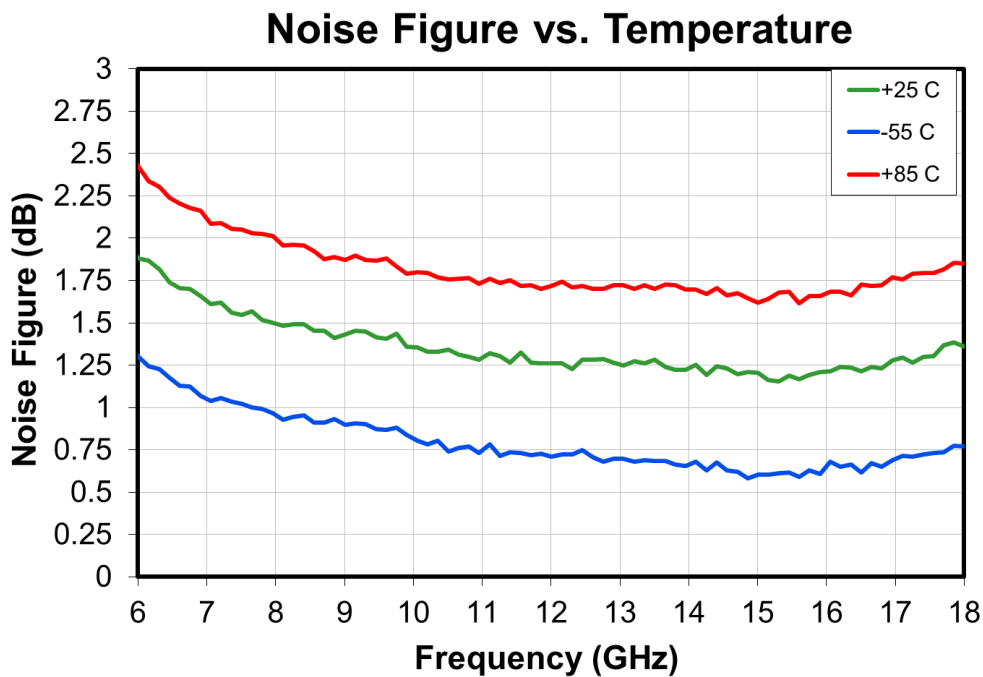
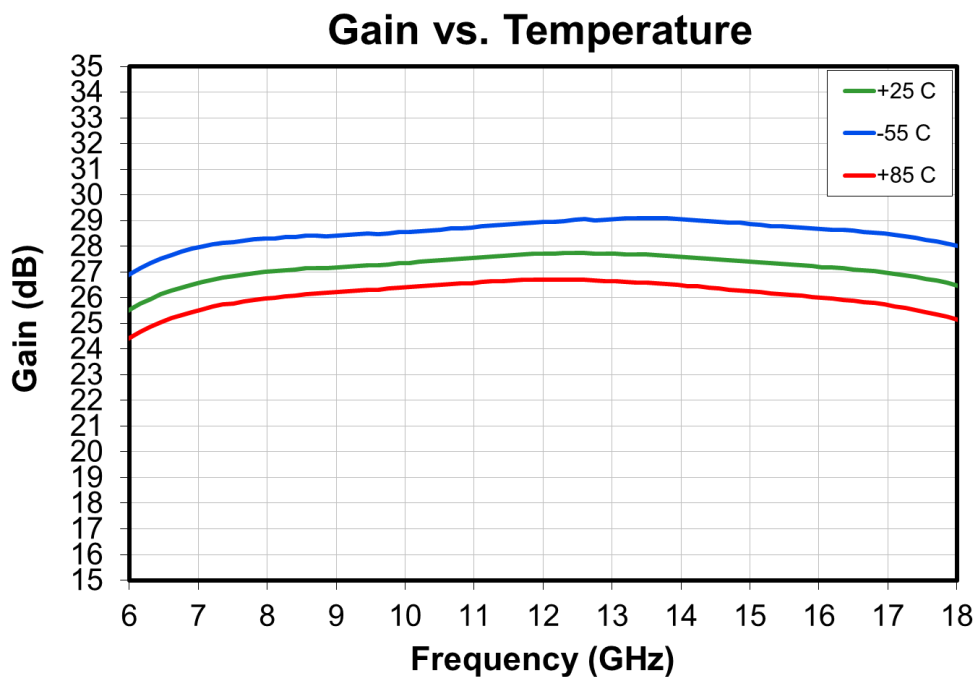
Test conditions unless otherwise noted: Vdd = 3V, T_A = 25 °C,

Parameter		Min	Typ.	Max	Units
RF Operational Frequency Range		6	–	18	GHz
Gain	Frequency = 6 – 9 GHz	-	26	–	dB
	Frequency = 9 – 18 GHz	-	27	–	
Noise Figure	Frequency = 6 – 9 GHz	–	1.6	-	dB
	Frequency = 9 – 18 GHz	–	1.25	-	
Input Return Loss	Frequency = 6 – 9 GHz	–	15	–	dB
	Frequency = 9 – 18 GHz	–	10	–	
Output Return Loss	Frequency = 6 – 9 GHz	–	20	–	dB
	Frequency = 9 – 18 GHz	–	17	–	
Output Power (P _{1dB})			12	–	dBm
Output IP3			24		dBm
Supply Current		-	52	-	mA
Gain Temperature Coefficient			-0.025		dB/°C
Noise Figure Temperature Coefficient			0.008		dB/°C

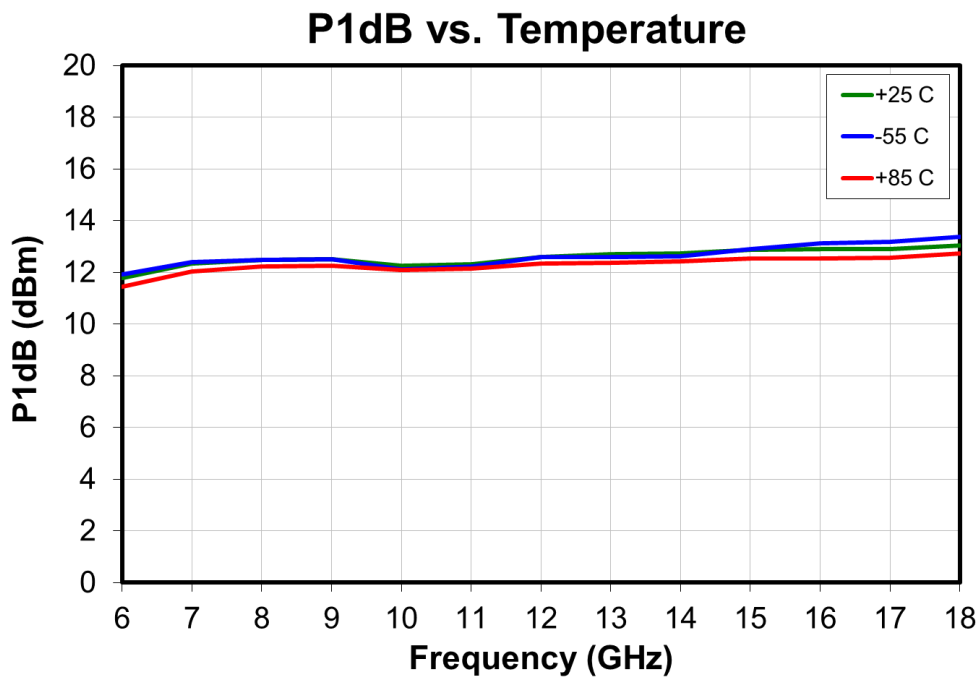
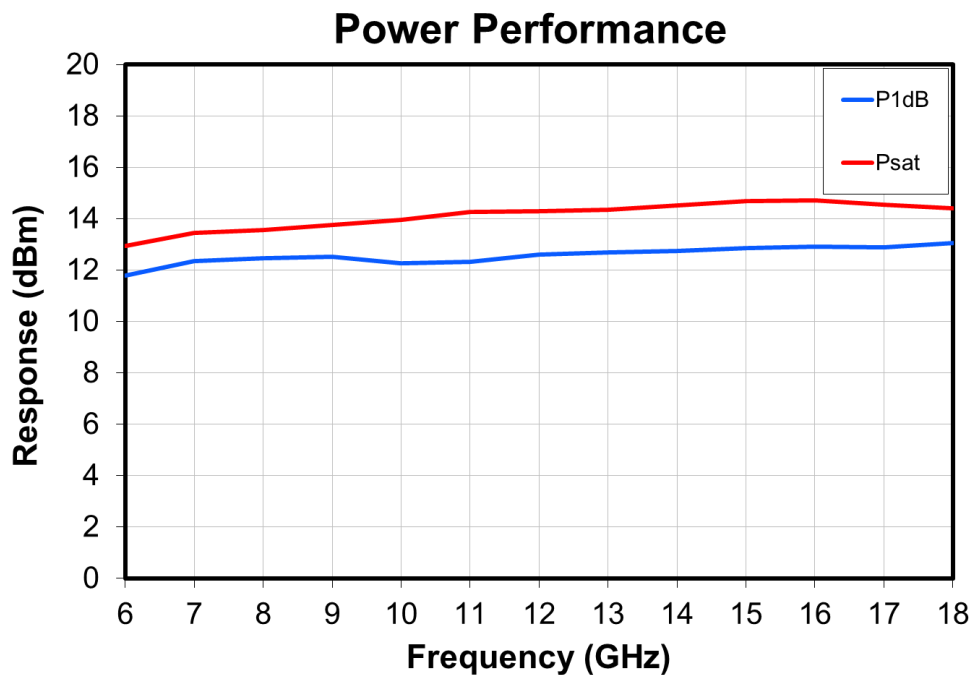
Typical Performance – $V_{dd} = 3\text{ V}$, $T_A = 25\text{ }^{\circ}\text{C}$



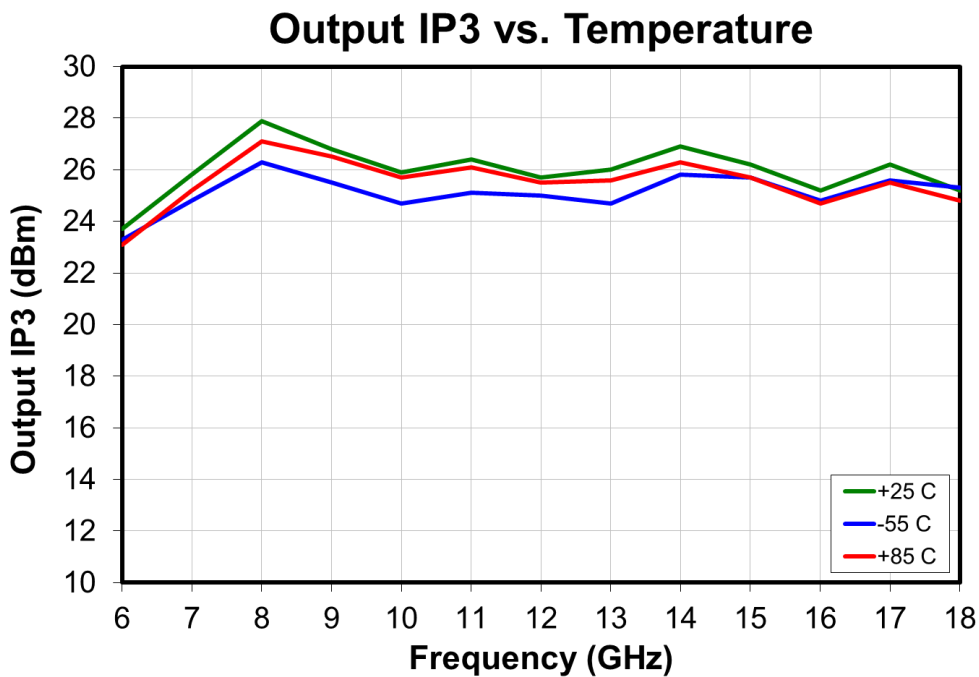
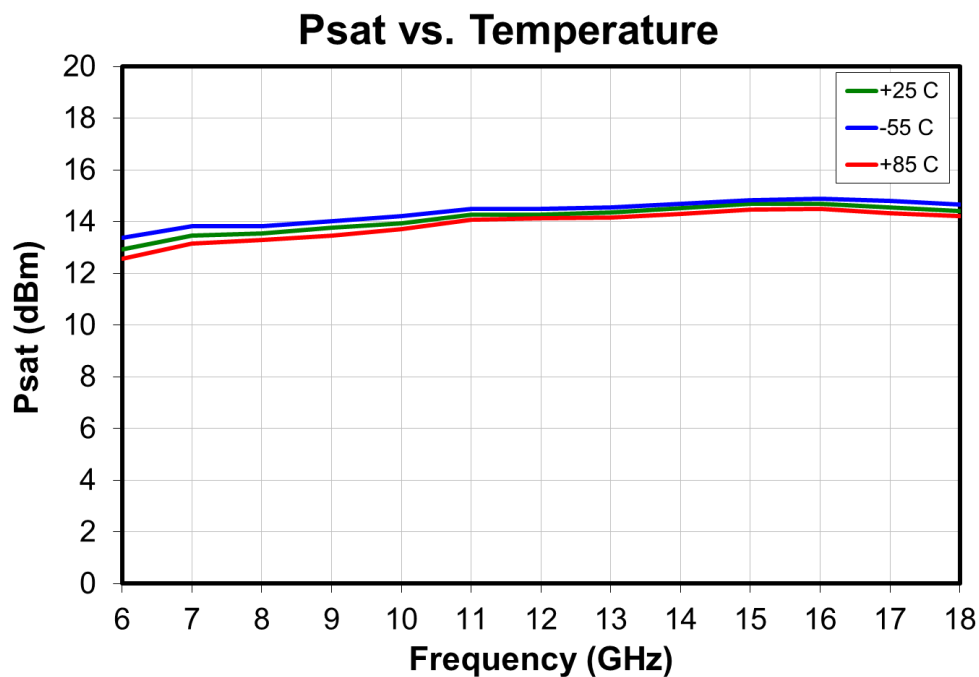
Typical Performance – Vdd = 3 V



Typical Performance – Vdd = 3 V



Typical Performance – $V_{dd} = 3\text{ V}$



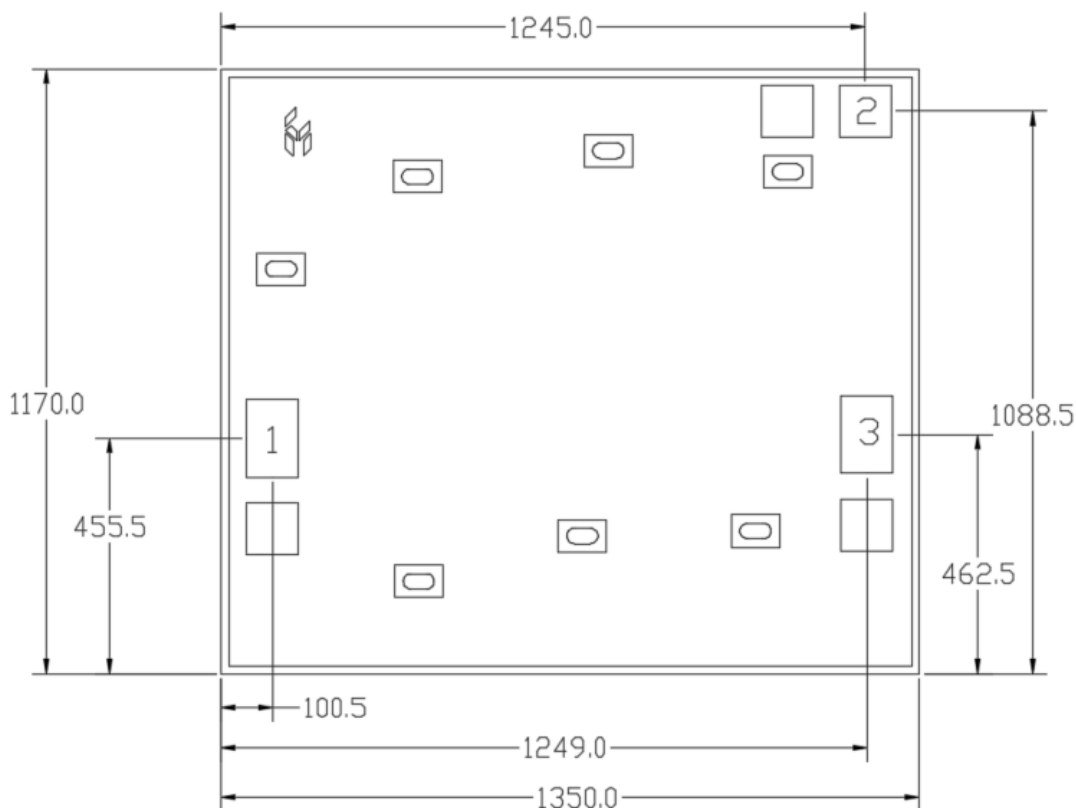
Thermal and Reliability Information

Parameter	Test Conditions	Value	Units
Thermal Resistance (θ_{JC}) ⁽¹⁾	$T_{BASE} = 85\text{ }^{\circ}\text{C}$, CW $P_{DISS} = 0.158\text{ W}$	158.8	$^{\circ}\text{C/W}$
Channel Temperature (T_{CH}) ⁽¹⁾		110	$^{\circ}\text{C}$
Median Lifetime (T_M)		3.87E7	Hrs

Notes:

1. Referenced to the back of the die.

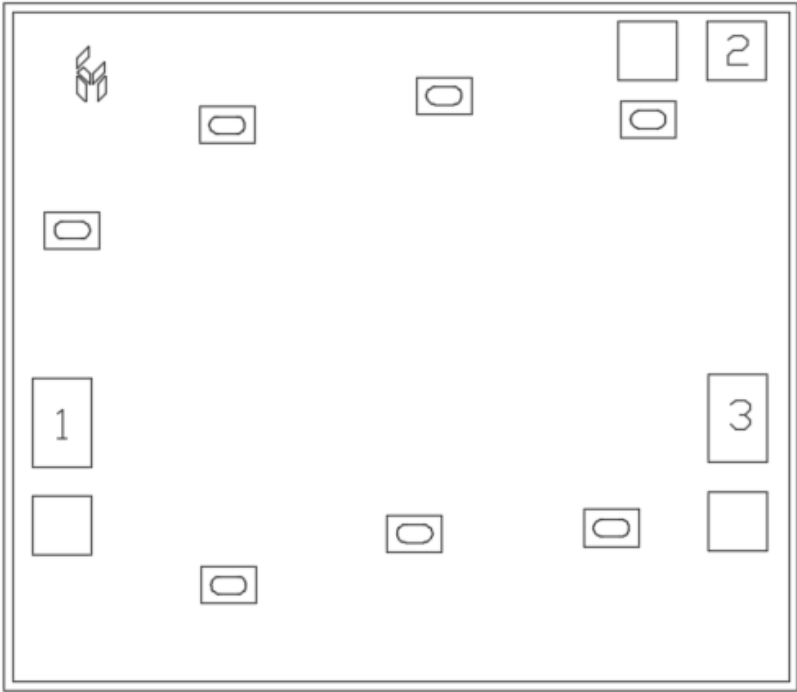
Mechanical Information



Notes:

1. All dimensions in microns.
2. No connection required for unlabeled grounds
3. Backside is RF and DC ground.
4. Backside and bond pad metal: Gold.
5. Die is 100 um thick.
6. Bond pads (1) and (3) are 150 x 100 um, bond pad (2) is 100 x 100 um.

Pin Diagram



Bond Pad Description

Pad No.	Symbol	Pad Size (um)	Description
1	RF in	100 x 150	This pin is AC coupled and matched to 50 Ohms.
2	Vdd	100 x 100	Power supply voltage. Decoupling and bypass capacitors required.
3	RF out	100 x 150	This pin is AC coupled and matched to 50 Ohms.
Backside	Ground		Connect to RF / DC ground

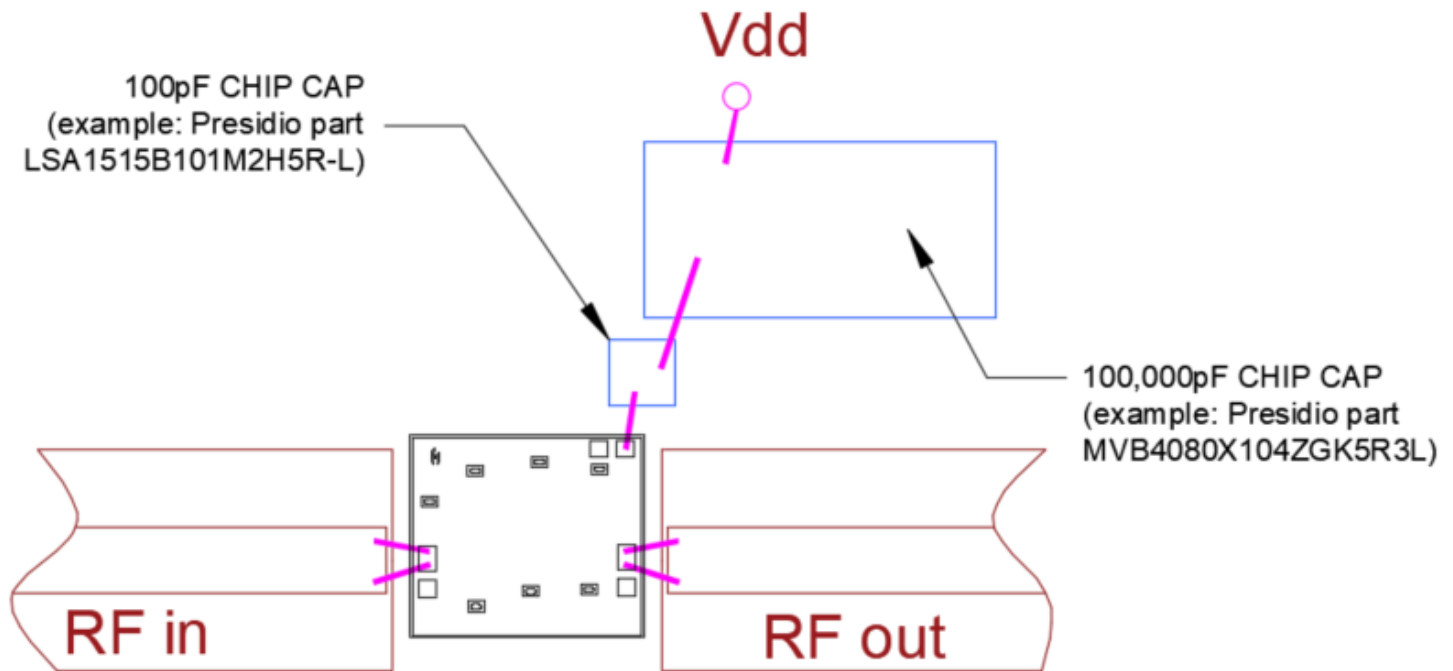
Assembly Guidelines

The backside of the CMD328 is RF ground. Die attach should be accomplished with electrically and thermally conductive epoxy only. Eutectic attach is not recommended. Standard assembly procedures should be followed for high frequency devices. The top surface of the semiconductor should be made planar to the adjacent RF transmission lines.

RF connections should be made as short as possible to reduce the inductive effect of the bond wire. Use of a 0.8 mil thermosonic wedge bonding is highly recommended as the loop height will be minimized.

The semiconductor is 100 μm thick and should be handled by the sides of the die or with a custom collet. Do not make contact directly with the die surface as this will damage the monolithic circuitry. Handle with care.

Assembly Diagram



Handling Precautions

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	TBD	ESDA / JEDEC JS-001-2012
MSL – Convection Reflow 235 °C	N/A	JEDEC standard IPC/JEDEC J-STD-020



Caution!
ESD-Sensitive Device

RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: www.qorvo.com

Tel: 1-844-890-8163

Email: customer.support@qorvo.com

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